MOSPEC

UE10C60C

Switchmode
Dual Ultrafast Power Rectifiers

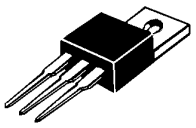
Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following:

Features

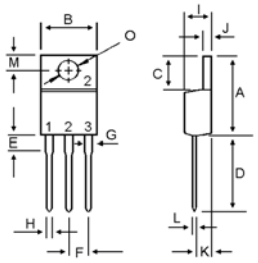
- ∗High Surge Capacity
- ∗Low Power Loss, High efficiency
- ∗150℃ Operating Junction Temperature
- ∗Low Stored Charge Majority Carrier Conduction
- ∗Low Forward Voltage , High Current Capability
- ∗High-Switching Speed Recovery Time
- ∗Plastic Material used Carries Underwriters Laboratory
- ∗Flammability Classification 94V-O
- ∗*Pb free*
- ∗*In compliance with EU RoHs directives*

Ultrafast Power
RECTIFIERS

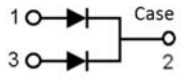
10 AMPERES
600 VOLTS



TO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	4.22	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00



MAXIMUM RATINGS

Characteristic	Symbol	UE10C60C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	420	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),T_C=100℃	$I_{F(AV)}$	5 10	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	10	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	100	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	℃

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage (I_F =5 Amp T_C = 25℃) (I_F =5 Amp T_C = 125℃)	V_F	--- ---	1.30 1.07	1.50 ---	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	--- ---	0.01 2	5.0 ---	uA
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	T_{rr}	---	---	50	ns
Typical Thermal Resistance junction to case	$R_{\theta jc}$		3.0		℃/w
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P		21		pF

FIG-1 TYPICAL FORWARD CHARACTERISTICS

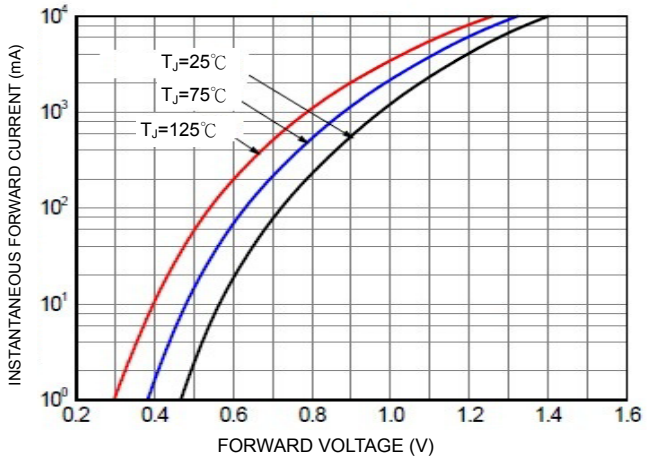


FIG-2 TYPICAL REVERSE CHARACTERISTICS

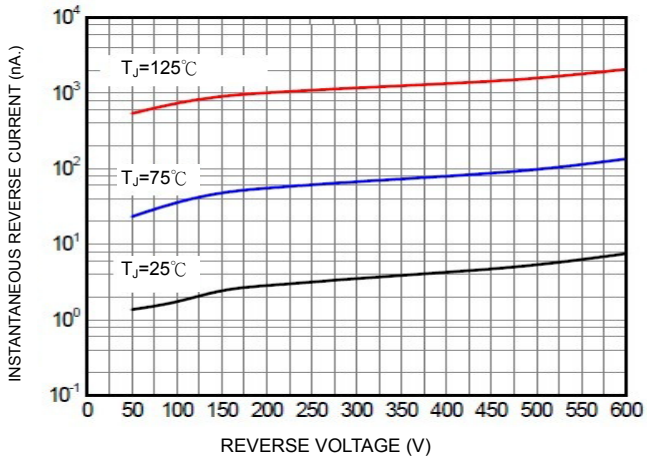


FIG-3 FORWARD CURRENT DERATING CURVE

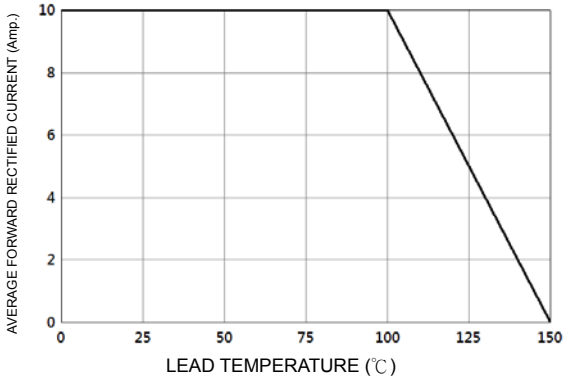


FIG-4 TYPICAL JUNCTION CAPACITANCE

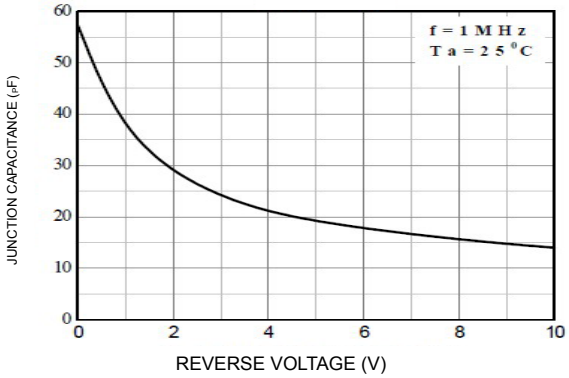
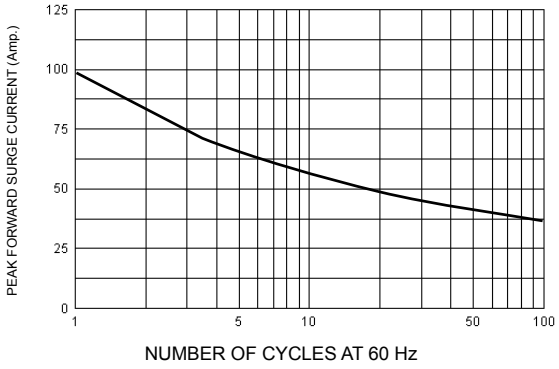
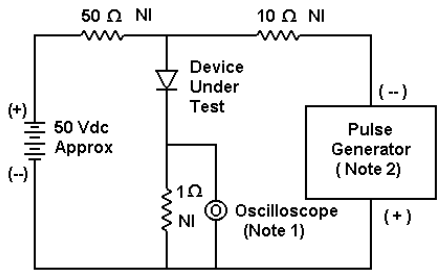
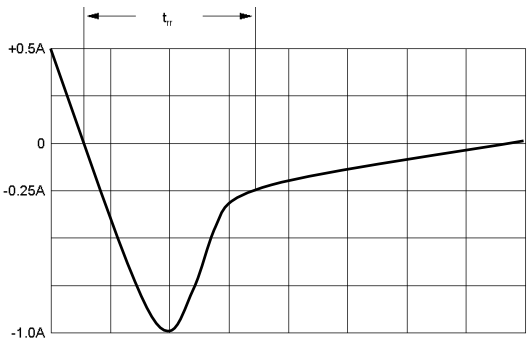


FIG-5 PEAK FORWARD SURGE CURRENT





Notes:
1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF
2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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